



2SA1708/2SC4488

High-Voltage Switching Applications

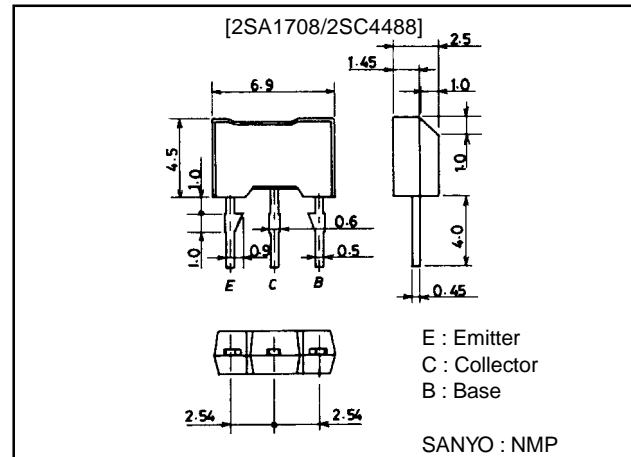
Features

- Adoption of FBET, MBIT processes.
- High breakdown voltage, large current capacity.
- Fast switching speed.

Package Dimensions

unit:mm

2064



() : 2SA1708

Specifications

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CB0}		(-)120	V
Collector-to-Emitter Voltage	V_{CEO}		(-)100	V
Emitter-to-Base Voltage	V_{EBO}		(-)6	V
Collector Current	I_C		(-)1	A
Collector Current (Pulse)	I_{CP}		(-)2	A
Collector Dissipation	P_C		1	W
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB} = (-)100\text{V}, I_E = 0$			(-)100	nA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = (-)4\text{V}, I_C = 0$			(-)100	nA
DC Current Gain	h_{FE}	$V_{CE} = (-)5\text{V}, I_C = (-)100\text{mA}$	100*		400*	
Gain-Bandwidth Product	f_T	$V_{CE} = (-)10\text{V}, I_C = (-)100\text{mA}$		120		MHz

* : The 2SA1708/2SC4488 are classified by 100mA h_{FE} as follows :

100	R	200	140	S	280	200	T	400
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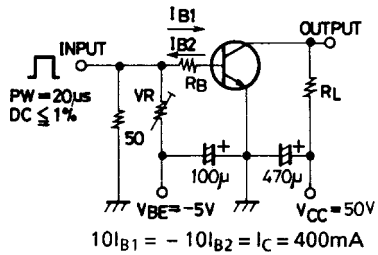
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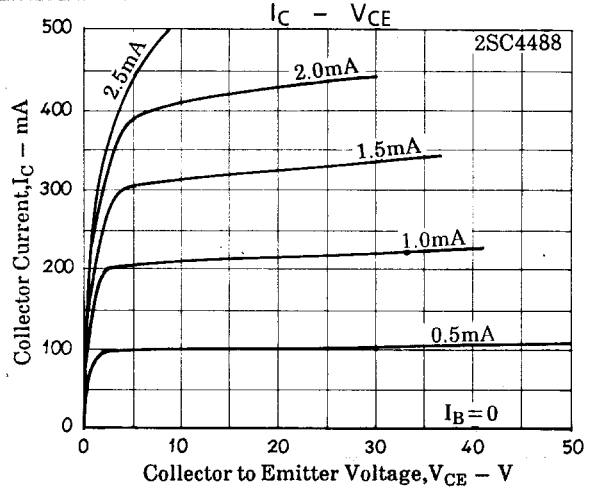
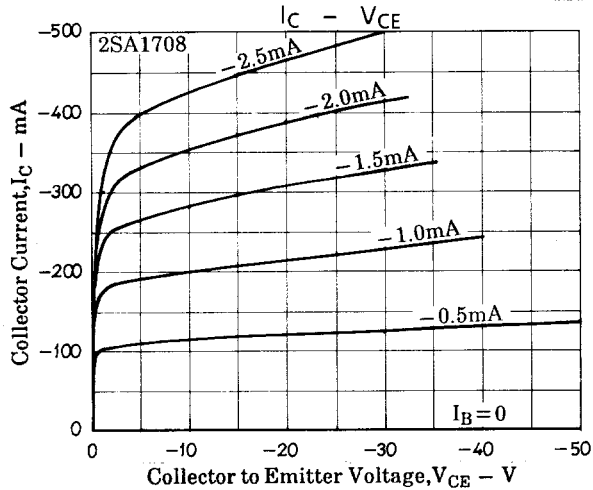
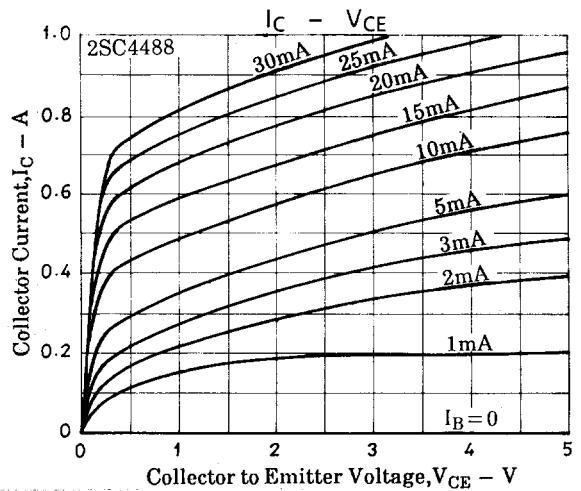
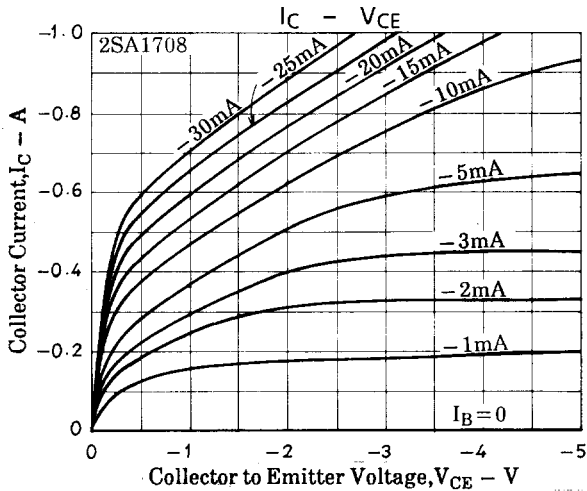
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)400mA, I_B=(-)40mA$		(-0.2)	(-0.6)	V
				0.1	0.4	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)400mA, I_B=(-)40mA$		(-)0.85	(-)1.2	V
Output Capacitance	C_{ob}	$V_{CB}=(-)10V, f=1MHz$		(13)8.5		pF
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-)120			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-)100			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$	(-)6			V
Turn-ON Time	t_{on}	See specified Test Circuit		80		ns
Storage Time	t_{stg}	See specified Test Circuit		(700)		ns
				850		ns
Fall Time	t_f	See specified Test Circuit		(40)50		ns

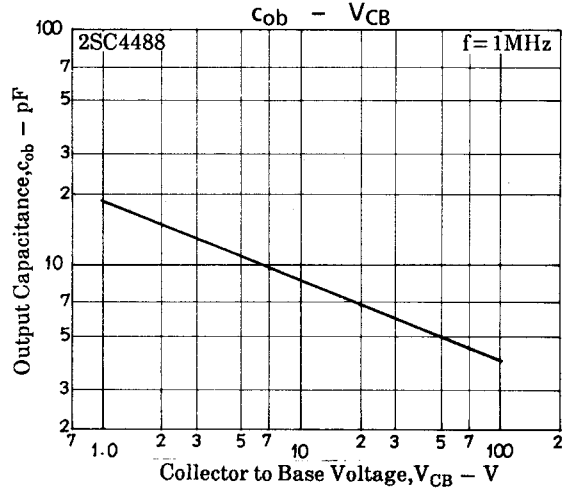
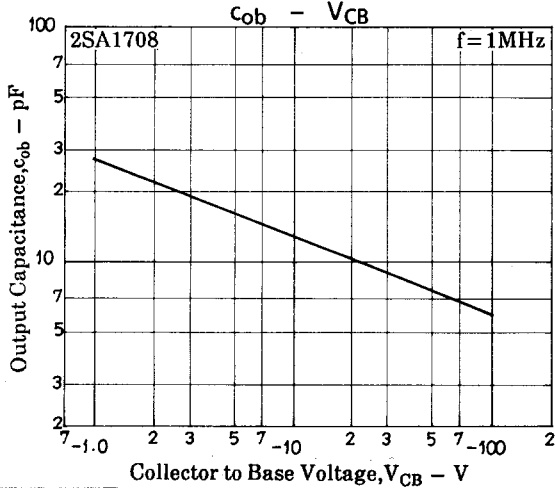
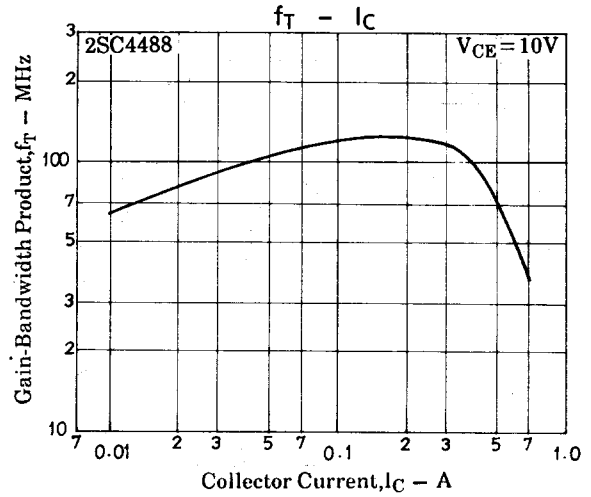
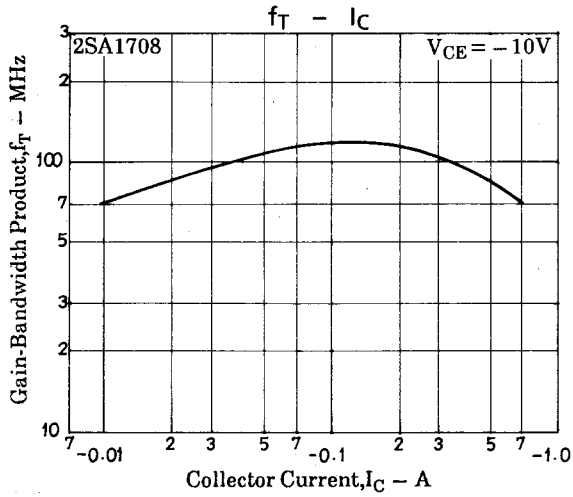
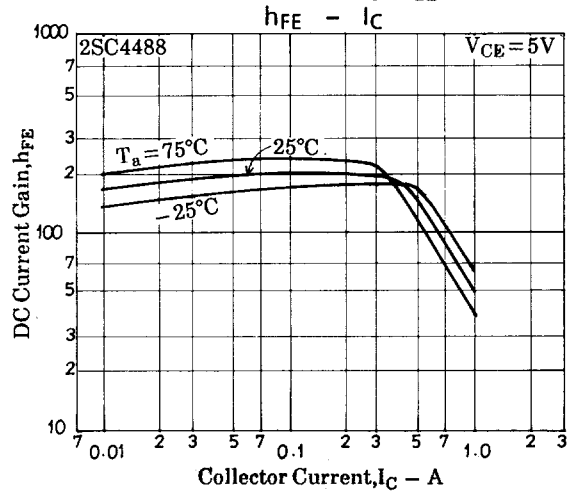
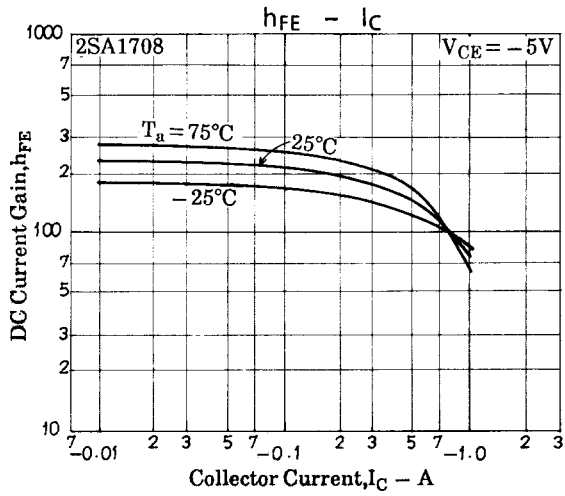
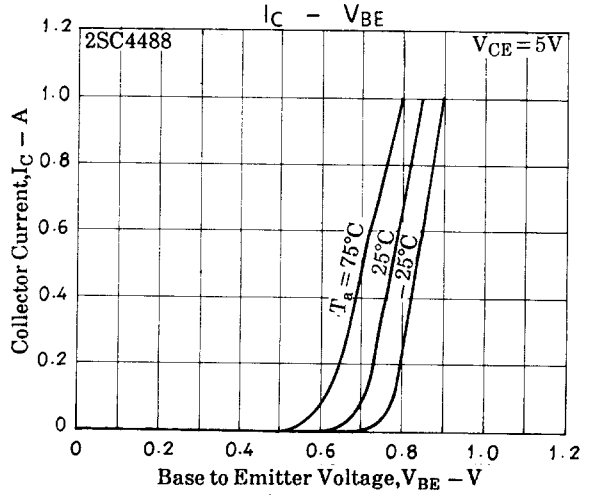
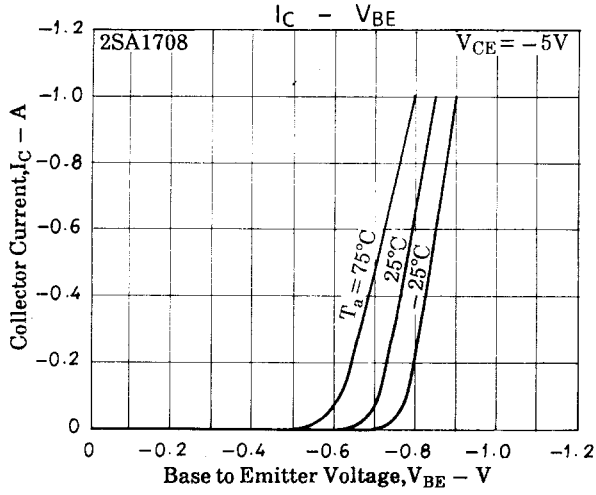
Switching Time Test Circuit



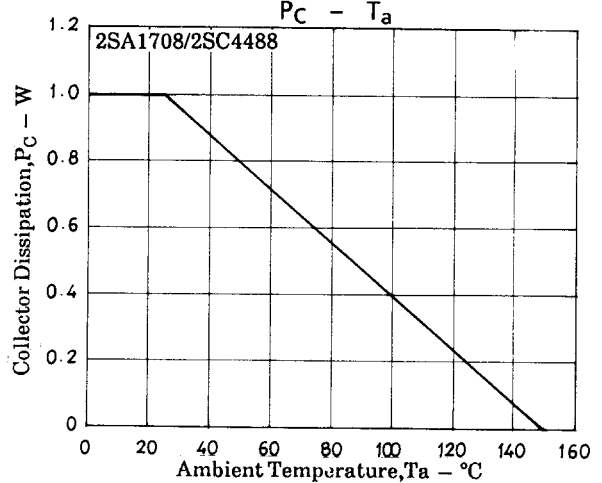
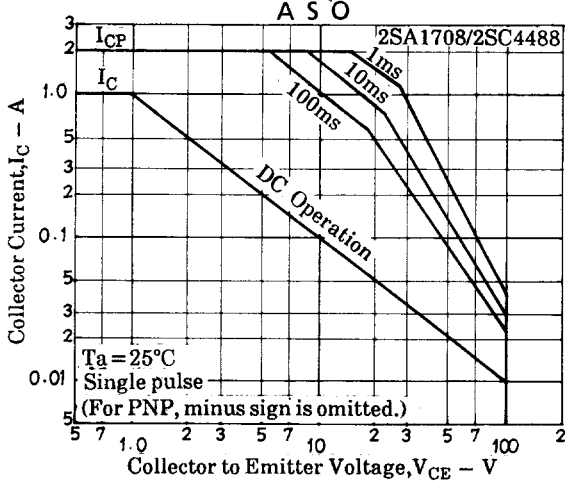
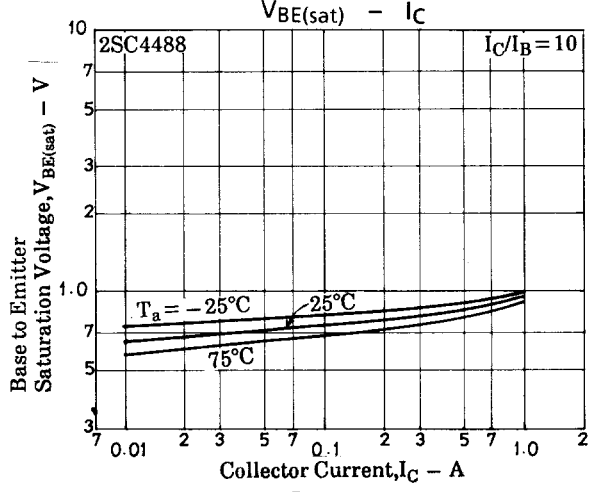
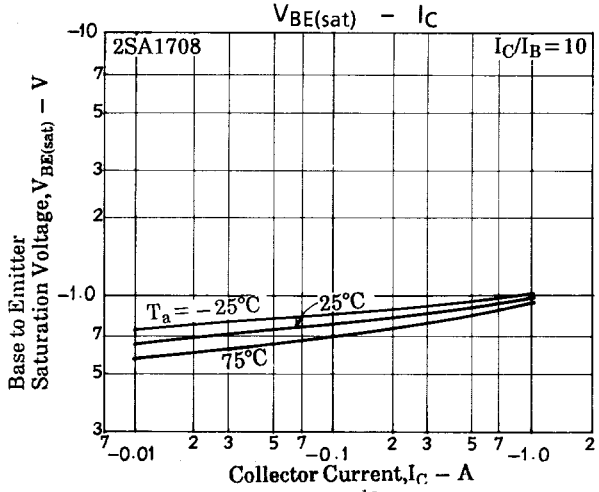
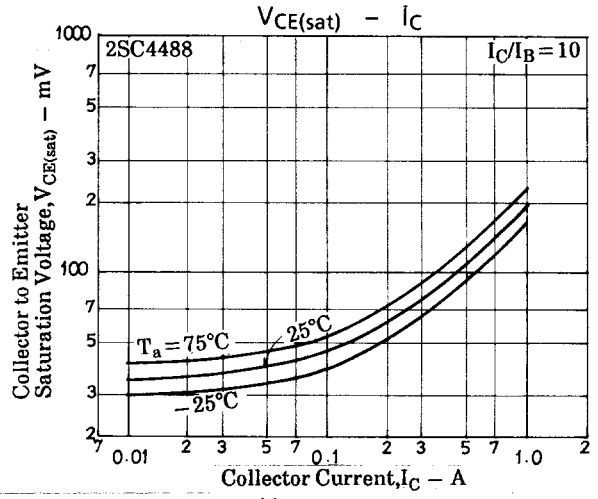
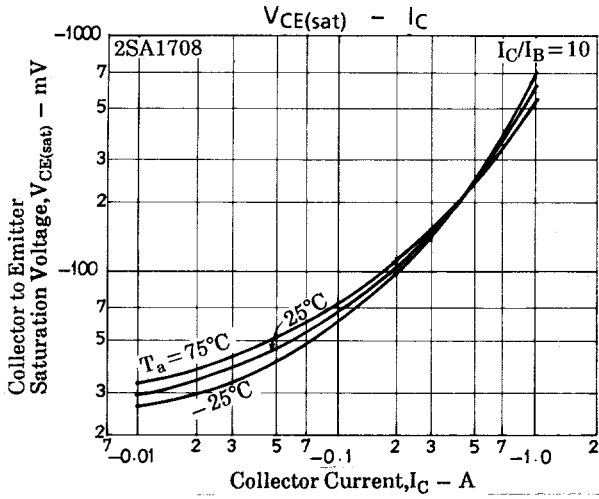
(For PNP, the polarity is reversed.)
Unit (resistance : Ω , capacitance : F)



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